## **Supporting Information**

## Thermally-Induced Agglomeration Tailors the Stability of Pt SAs on TiO<sub>2</sub> and Use in Photocatalytic H<sub>2</sub> Generation

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Figure S1. SEM cross-sectional image of a 20 nm thick as-deposited TiO<sub>2</sub> layer on SiO<sub>2</sub> with

identical deposition parameters as for the gas cell experiments.



**Figure S2**. Time resolved hydrogen evolution data of samples with different thermal preannealing treatments in Ar atmosphere as compared to the non-treated sample.



Figure S3. Raman spectra of the  $TiO_2$  thin-films (deposited in a 2 mM H<sub>2</sub>PtCl<sub>6</sub> solution)

annealed at different temperatures.



Figure S4. EDXS mapping of a  $TiO_2$  thin film loaded with Pt after annealing at 550 °C for 1h. The  $TiO_2$  composition of the area indicated on the bottom right yields a composition of 70 at% O and 30 at% Ti.



**Figure S5**. Pt 4f XPS spectra of Pt on TiO2 after different thermal pre-treatments before (left) and after (right) photocatalysis for 3h illumination (275 nm, 30 mW).



Figure S6. Scheme of the experimental setup. The electron beam is focused on the Pt containing  $TiO_2$  surface, which is exposed to an Ar gas flow. The gas flow is constrained within the gas cell, while observations are enabled by several ten nanometer thick  $Si_3N_4$  windows.



**Figure S7**. *In situ* SAED patterns of an amorphous  $TiO_2$  film (left image) heated to 400 °C (heating rate 100°C s<sup>-1</sup>) in Ar atmosphere. The film starts to crystallize within 20 s (center image) and already exhibits its final polycrystalline nature after 2 min (right image). The pattern does not further change after 30 min at 400 °C.



Figure S8. Measured temperature profiles of the heating experiments in Ar atmosphere for the samples produced at different  $H_2PtCl_6$  concentrations: a) 0.05 mM; b) 0.005 mM.



**Figure S9**. HAADF-STEM characterization at lower magnification in the same area, as in Figure 4.



Figure S10. Identical-location HAADF-STEM images of the Pt SA decorated  $TiO_2$  layer (using 0.05 mM H<sub>2</sub>PtCl<sub>6</sub>) heated in Ar atmosphere (700 mbar) to different temperatures (250–950 °C). The images are taken at a different site from that in the main text.



**Figure S11**. High magnification *ex situ* HAADF-STEM images of the Pt SA decorated  $TiO_2$  layer (thermally treated following the procedure in Figure 4) after cooling down to room temperature. Remaining Pt agglomerates coexist with Pt SAs homogeneously distributed over the  $TiO_2$  surface (the white bar corresponds to 2 nm).



**Figure S12**. Identical-location HAADF-STEM images of the Pt SA decorated  $TiO_2$  surface taken *in situ* at 950 °C (thermally treated following the procedure in Figure 4) and *ex situ* upon cooling down to room temperature. The left and right images taken at room temperature can be compared to Figure 4 (950 °C) and Figure S8 (950 °C), respectively.



Figure S13. Hydrogen evolution data of the sample annealed at 950  $^\circ$ C as compared to

the other samples.



**Figure S14**. Low magnification *in situ* HAADF-STEM images of the Pt SA decorated (using 0.005 mM H<sub>2</sub>PtCl<sub>6</sub>) amorphous TiO<sub>2</sub> layer heated in Ar atmosphere (700 mbar) to 400 °C (left) and 900 °C (right). The images reveal an overall low degree of agglomeration.



**Figure S15**. Relationship of the structural SA density as determined by STEM with the  $Pt^{\delta^+}$  fraction as determined by XPS after thermally-induced (red) and light-induced agglomeration

(blue).